SQJ409EP

RoHS

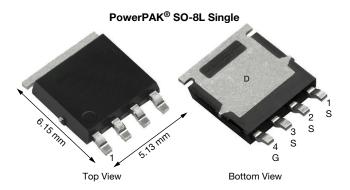
COMPLIANT HALOGEN

FREE

www.vishay.com

Vishay Siliconix

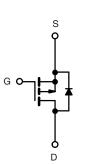
Automotive P-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY	
V _{DS} (V)	-40
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 V$	0.0070
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0100
I _D (A)	-60
Configuration	Single

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ409EP (for detailed order number please see <u>www.vishay.com/doc?79771</u>)

ABSOLUTE MAXIMUM RATINGS (T _C =	= 25 °C, unles	ss otherwise noted	ł)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	-40	v
Gate-source voltage		V _{GS}	± 20	v
Continuous drain current	T _C = 25 °C ª	1	-60	
	T _C = 125 °C	I _D	-42	
Continuous source current (diode conduction) ^a		ا _S	-60	А
Pulsed drain current ^b		I _{DM}	-150	
Single pulse avalanche current		I _{AS}	-41	
Single pulse avalanche energy		E _{AS}	84	mJ
Maximum power dissipation ^b	T _C = 25 °C	PD	68	w
Maximum power dissipation ~	T _C = 125 °C	°C 22		vv
Operating junction and storage temperature range	T _J , T _{stg}	-55 to +175		
Soldering recommendations (peak temperature) d, e			260	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	68	°C/W
Junction-to-case (drain)		R _{thJC}	2.2	0/10

Notes

a. Package limited

- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

1

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

S22-0224-Rev. B, 07-Mar-2022

For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> www.vishay.com

SQJ409EP

Vishay Siliconix

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static	•	•					
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = -250 \ \mu A$		-40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V_{GS} , I_D = -250 μ A	-1.5	-2.0	-2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μA
		$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	-150	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \ge -5 V$	-30	-	-	Α
		V _{GS} = -10 V	I _D = -10 A	-	0.0058	0.0070	
Drain aguras en stata registance à		V _{GS} = -10 V	I _D = -10 A, T _J = 125 °C	-	-	0.0106	Ω
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0126	
		V _{GS} = -4.5 V	I _D = -6 A	-	0.0083	0.0100	
Forward transconductance b	9 _{fs}	V _{DS} = -15 V, I _D = -10 A		-	54	-	S
Dynamic ^b	•	•					
Input capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	8400	11 000	pF
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	620	850	
Reverse transfer capacitance	C _{rss}			-	510	700	
Total gate charge ^c	Qg			-	170	260	
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -20 \text{ V}, \text{ I}_{D} = -5 \text{ A}$	-	24	-	nC
Gate-drain charge ^c	Q _{gd}			-	35	-	
Gate resistance	Rg		f = 1 MHz	0.50	1.08	1.70	Ω
Turn-on delay time ^c	t _{d(on)}			-	23	35	- ns
Rise time ^c	t _r	V _{DD} :	= -20 V, R_{L} = 4 Ω	-	18	30	
Turn-off delay time ^c	t _{d(off)}	I _D ≅ -5 Å, \	$V_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	75	120	
Fall time ^c	t _f			-	12	20	
Source-Drain Diode Ratings and Chara	cteristics ^b	•					
Pulsed current ^a	I _{SM}			-	-	-150	Α
Forward voltage	V _{SD}	I _F =	-10 A, V _{GS} = 0 V	-	-0.76	-1.2	V
Body diode reverse recovery time	t _{rr}	I _F = -10 A, di/dt = 100 A/μs		-	39	90	ns
Body diode reverse recovery charge	Q _{rr}			-	45	100	nC
Reverse recovery fall time	ta			-	22	-	
Reverse recovery rise time	t _b			-	19	-	ns
Body diode peak reverse recovery					-2.3		А

Notes

f. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

g. Guaranteed by design, not subject to production testing

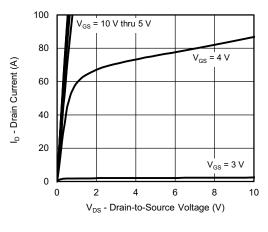
h. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

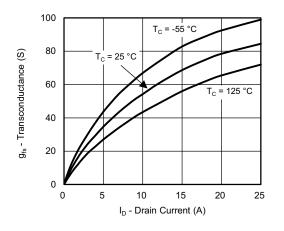
2



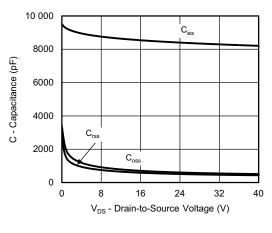
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



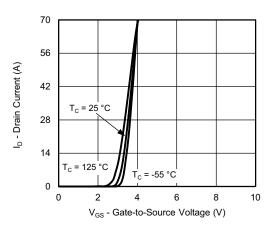
Output Characteristics



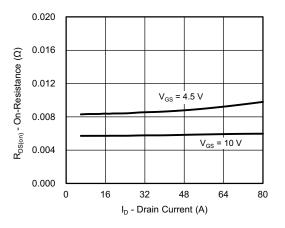
Transconductance



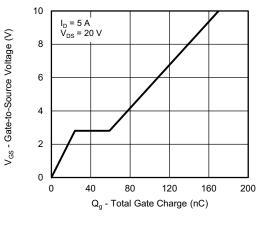
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current



Gate Charge

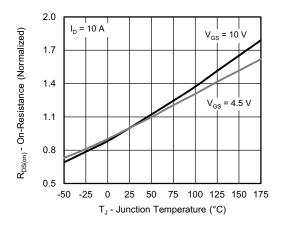
S22-0224-Rev. B, 07-Mar-2022

3 ons contact automostechsur Document Number: 77707

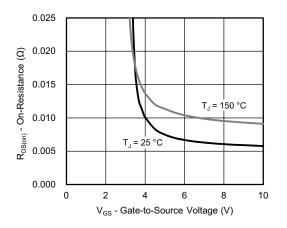
For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



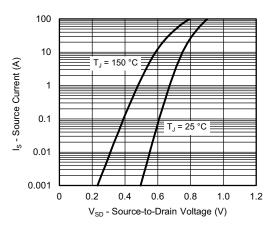
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



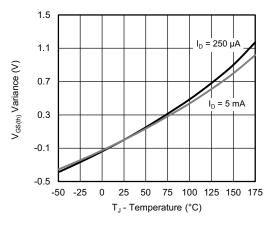
On-Resistance vs. Junction Temperature



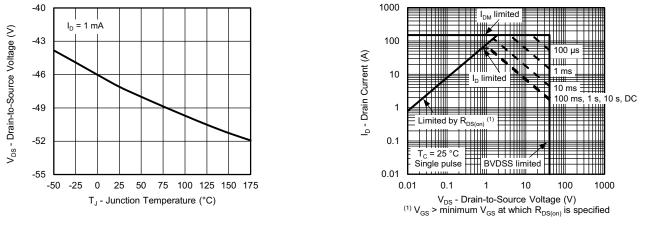
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



Drain-Source Breakdown vs. Junction Temperature

Safe Operating Area

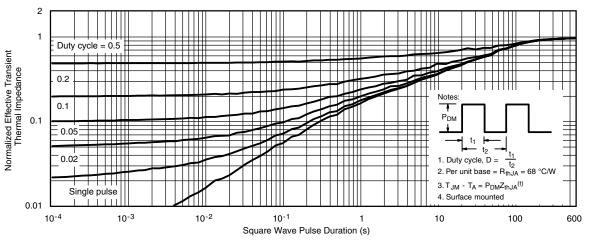
4

Document Number: 77707

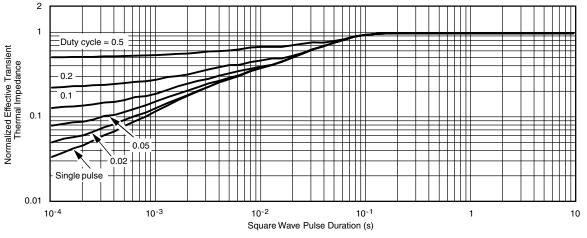
For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?77707</u>.

S22-0224-Rev. B, 07-Mar-2022	5	Document Number: 77707
	For technical questions, contact: automostechsupport@vishay.com	<u>m</u>
	T TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED	
ARE SUBJ	IECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishav.cor</u>	<u>m/doc?91000</u>









THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Package Information



Vishay Siliconix

DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К		0.51			0.020		
W		0.23			0.009		
W1		0.41			0.016		
W2		2.82			0.111		
W3		2.96			0.117		
θ	0°	-	10°	0°	-	10°	

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK[®] SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)

Revision: 07-Feb-12



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.